







SN54HC253, SN74HC253 SCLS133F - DECEMBER 1982 - REVISED FEBRUARY 2022

# SNx4HC253 Dual 4-Line To 1-Line Data Selectors/Multiplexers With 3-State Outputs

#### 1 Features

- 3-State version of 'HC153
- Wide operating voltage range of 2 V to 6 V
- High-current inverting outputs drive up to 15 LSTTL loads
- Low power consumption, 80- $\mu$ A max I<sub>CC</sub>
- Typical  $t_{pd} = 9 \text{ ns}$
- ±6-mA output drive at 5 V
- Low input current of 1 µA max
- Permit multiplexing from n lines to one line
- Perform parallel-to-serial conversion

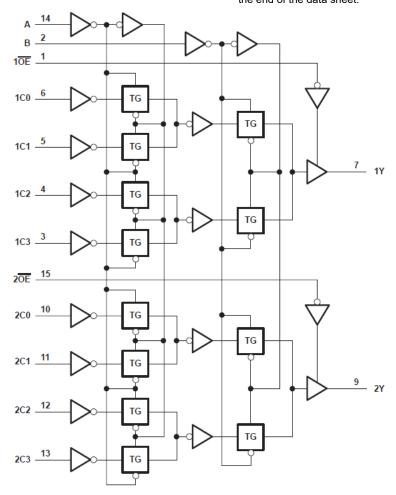
### 2 Description

The SNx4HC253 devices contain two independent data selectors/multiplexers with full binary decoding to select 1-of-4 data sources and features strobecontrolled (OE) 3-state outputs.

#### **Device Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	BODY SIZE (NOM)
SN74HC253D	SOIC (16)	9.90 mm × 3.90 mm
SN74HC253DB	SSOP (16)	6.20 mm × 5.30 mm
SN74HC253N	PDIP (16)	19.31 mm × 6.35 mm
SN74HC253NS	SO (16)	6.20 mm × 5.30 mm
SN54HC253J	CDIP (16)	24.38 mm × 6.92 mm
SNJ54HC253FK	LCCC (20)	8.89 mm × 8.45 mm

For all available packages, see the orderable addendum at the end of the data sheet.



Pin numbers shown are for the D, DB, J, N, NS, and W packages.

#### **Functional Block Diagram**



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## **3 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

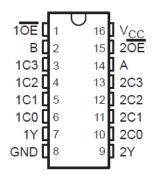
### Changes from Revision E (September 2003) to Revision F (February 2022)

Page

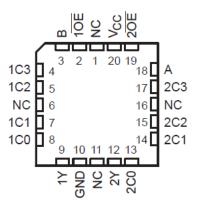
 Updated numbering, formating, tables, figures, and cross-references throughout the document to reflect modern data sheet standards......



# **4 Pin Configuration and Functions**



J, D, DB, N, or NS Package 16-Pin CDIP, SOIC, SSOP, PDIP, SO Top View



NC - No internal connection

FK Package 20-Pin LCCC Top View



## **5 Specifications**

## 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		<u> </u>	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	V
I <sub>IK</sub>	Input clamp current <sup>(2)</sup>	$V_I < 0 \text{ or } V_I > V_{CC}$		±20	mA
I <sub>OK</sub>	Output clamp current <sup>(2)</sup>	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to $V_{CC}$		±25	mA
	Continuous current through V <sub>CC</sub> or GN	ID .		±50	mA
TJ	Junction temperature			150	°C
T <sub>stg</sub>	Storage temperature		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 5.2 Recommended Operating Conditions<sup>(1)</sup>

			SN54HC253			SN		UNIT		
			MIN	NOM	MAX	MIN	NOM	MAX	ONII	
V <sub>CC</sub>	Supply voltage		2	5	6	2	5	6	V	
		V <sub>CC</sub> = 2 V	1.5			1.5				
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 4.5 V	3.15			3.15			V	
	V <sub>CC</sub> = 6 V	4.2			4.2					
		V <sub>CC</sub> = 2 V			0.5			0.5		
V <sub>IL</sub> Low-level input voltage	V <sub>CC</sub> = 4.5 V			1.35			1.35	V		
		V <sub>CC</sub> = 6 V			1.8			1.8		
VI	Input voltage	•	0		V <sub>CC</sub>	0		V <sub>CC</sub>	V	
Vo	Output voltage		0		V <sub>CC</sub>	0		V <sub>CC</sub>	V	
		V <sub>CC</sub> = 2 V			1000			1000		
Δt/Δν	Δt/Δv Input transition rise/fall time	V <sub>CC</sub> = 4.5 V			500			500	ns	
		V <sub>CC</sub> = 6 V			400			400		
T <sub>A</sub>	Operating free-air temperature	•	-55		125	-40		85	°C	

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

### 5.3 Thermal Information

		D (SOIC)	DB (SSOP)	N (PDIP)	NS (SO)	
THERM	MAL METRIC <sup>(1)</sup>	16 PINS	16 PINS	16 PINS	16 PINS	UNIT
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	73	82	67	64	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

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<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



#### **5.4 Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS <sup>(1)</sup>	V 00	T,	<sub>A</sub> = 25°C		SN54HC	253	SN74HC	253	UNIT
PARAMETER	TEST CONDITIONS	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONIT
		2	1.9	1.998		1.9		1.9		
$V_{OH}$ $I_{OH} = -20 \mu A$ $I_{OH} = -6 \text{ mA}$	I <sub>OH</sub> = -20 μA	4.5	4.4	4.499		4.4		4.4		
		6	5.9	5.999		5.9		5.9		V
	I <sub>OH</sub> = −6 mA	4.5	3.98	4.3		3.7		3.84		
	$I_{OH} = -7.8 \text{ mA}$		5.48	5.8		5.2		5.34		
		2		0.002	0.1		0.1		0.1	
	I <sub>OL</sub> = 20 μA	4.5		0.001	0.1		0.1		0.1	
$V_{OL}$		6		0.001	0.1		0.1		0.1	V
	I <sub>OL</sub> = 6 mA	4.5		0.17	0.26		0.4		0.33	
	I <sub>OL</sub> = 7.8 mA	6		0.15	0.26		0.4		0.33	
I <sub>I</sub>	V <sub>I</sub> = V <sub>CC</sub> or 0	6		±0.1	±100		±1000		±1000	nA
l <sub>oz</sub>	V <sub>O</sub> = V <sub>CC</sub> or 0	6		±0.01	±0.5		±10		±5	μA
I <sub>CC</sub>	$V_I = V_{CC}$ or $0$ $I_O = 0$	6			8		160		80	μA
C <sub>i</sub>	,	2 to 6		3	10		10		10	pF

<sup>(1)</sup>  $V_I = V_{IH}$  or  $V_{IL}$ , unless otherwise noted.

## **5.5 Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 6)

PARAMETER	FROM	то	V <sub>CC</sub> (V)	T <sub>A</sub> =	25°C		SN54HC253	SN74HC253	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	VCC (V)	MIN	TYP	MAX	MIN MA	MIN MAX	ONIT	
			2		62	150	22	190		
	A or B	Any Y	4.5		19	30	4	38		
• .			6		16	26	3	32	ns	
t <sub>pd</sub> Data (Any C)		2		54	126	21	175	115		
	Y	4.5		16	28	4.	2 35			
		6		13	23	3	30			
		2		28	100	15	125			
t <sub>en</sub>	ŌĒ	Y	4.5		11	20	3	25	ns	
			6		9	17	2	3 21		
			2		21	135	20	170		
t <sub>dis</sub>	ŌĒ	Y	4.5		14	30	4	38	ns	
			6		12	35	3	31		
			2		28	60	9	75	ns	
t <sub>t</sub>		Y	4.5		8	12	1	15		
			6		6	10	1	13		



# **5.6 Switching Characteristics**

over recommended operating free-air temperature range,  $C_L$  = 150 pF (unless otherwise noted) (see Figure 6)

PARAMETER	FROM	то	V <sub>cc</sub> (V)	TA	= 25°C		SN54HC253	SN74HC253	UNIT
PARAMETER	(INPUT)	(OUTPUT)	VCC (V)	MIN	TYP	MAX	MIN MAX	MIN MAX	ONIT
			2		76	235	355	295	
	A or B	Any Y	4.5		23	47	71	59	
t <sub>pd</sub> Data (Any C)		6		20	41	60	51	ns	
	Y	2		68	220	335	275	115	
		4.5		20	44	67	55		
	(/)		6		17	38	57	51	
			2		44	185	280	230	
t <sub>en</sub>	ŌĒ	Y	4.5		16	37	56	46	ns
			6		14	32	48	40	
			2		45	210	315	265	
t <sub>t</sub>		Y	4.5		17	42	63	53	ns
			6		13	36	53	45	

# **5.7 Operating Characteristics**

T<sub>A</sub> = 25°C

	PARAMETER	TEST CONDITIONS	TYP	UNIT
$C_{pd}$	Power dissipation capacitance per multiplexer	No load	45	pF

#### **6 Parameter Measurement Information**

 $t_{\text{pd}}$  is the maximum between  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$ 

 $t_{t}$  is the maximum between  $t_{\text{TLH}}$  and  $t_{\text{THL}}$ 

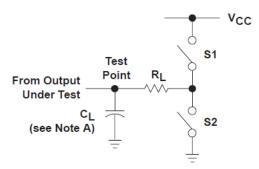


Figure 6-1. Load Circuit

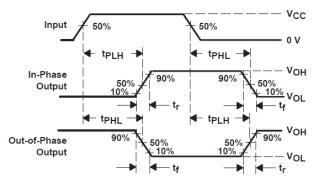
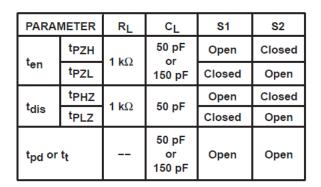


Figure 6-2. Voltage Waveforms
Propagation Delay and Output Transition Times



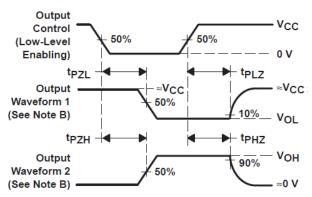


Figure 6-3. Voltage Waveforms
Enable and Disable Times for 3-State Outputs

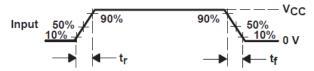


Figure 6-4. Voltage Waveform Input Rise and Fall Times

- A. C<sub>L</sub> includes probe and test-fixture capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when diabled by the output control.
- Waveform 2 is for an output with internal conditions such that the output is high except when diabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following charactersitics: PRR  $\leq$  1 MHz,  $Z_O$  = 50  $\Omega$ ,  $t_r$  = 6 ns,  $t_f$  = 6 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.

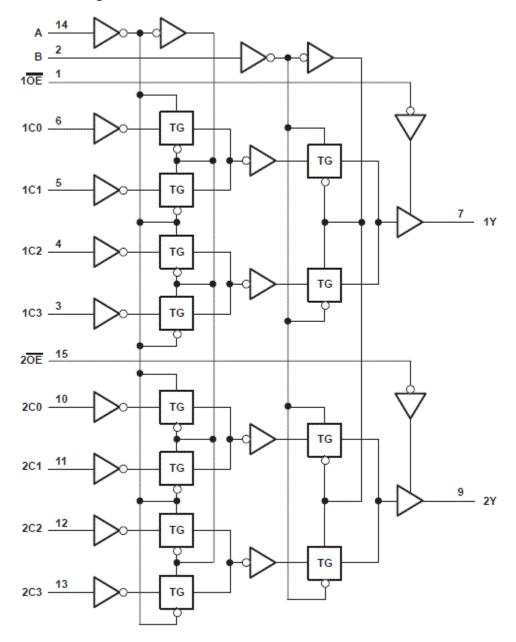
## 7 Detailed Description

### 7.1 Overview

Each of these data selectors/multiplexers contains inverters and drivers to supply full binary decoding data selection to the AND-OR gates. Separate output-control inputs are provided for each of the two 4-line sections.

The 3-state outputs can interface with and drive data lines of bus-organized systems. With all but one of the common outputs disabled (in the high-impedance state), the low impedance of the single enabled output drives the bus line to a high or low logic level. Each output has its own output-enable  $(\overline{OE})$  input. The outputs are disabled when their respective  $\overline{OE}$  is high.

### 7.2 Functional Block Diagram





## 7.3 Device Functional Modes

**Table 7-1. Function Table** 

	INPUTS							
SELE	CT <sup>(1)</sup>		DA	<b>TA</b>		ŌĒ	OUTPUT Y	
В	Α	C0	C1	C2	C3	OE		
Х	Х	Х	Х	Х	Х	Н	Z	
L	L	L	Х	Х	Х	L	L	
L	L	Н	Х	Х	Х	L	Н	
L	Н	Х	L	Х	Х	L	L	
L	Н	Х	Н	Х	Х	L	Н	
Н	L	Х	Х	L	Х	L	L	
Н	L	Х	Х	Н	Х	L	Н	
Н	Н	Х	Х	Х	L	L	L	
Н	Н	Х	Х	Х	Н	L	Н	

<sup>(1)</sup> Select inputs A and B are common to both sections.

## 8 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- $\mu$ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

#### 9 Layout

#### 9.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.



## 10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

#### 10.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 10.2 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 10.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



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#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-88682012A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 88682012A SNJ54HC 253FK	Samples
5962-8868201EA	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8868201EA SNJ54HC253J	Samples
SN54HC253J	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	SN54HC253J	Samples
SN74HC253DBR	ACTIVE	SSOP	DB	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC253	Samples
SN74HC253DR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	HC253	Samples
SN74HC253N	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HC253N	Samples
SN74HC253NE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HC253N	Samples
SN74HC253NSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC253	Samples
SNJ54HC253FK	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 88682012A SNJ54HC 253FK	Samples
SNJ54HC253J	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8868201EA SNJ54HC253J	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".



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**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN54HC253, SN74HC253:

Catalog: SN74HC253

Automotive: SN74HC253-Q1, SN74HC253-Q1

Enhanced Product: SN74HC253-EP, SN74HC253-EP

Military: SN54HC253

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

# **PACKAGE OPTION ADDENDUM**

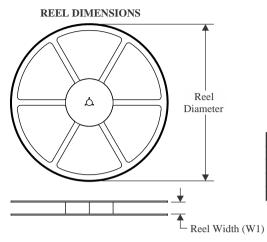
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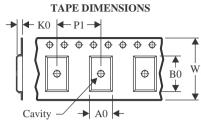
• Military - QML certified for Military and Defense Applications

# **PACKAGE MATERIALS INFORMATION**

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### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC253DBR	SSOP	DB	16	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74HC253DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HC253NSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74HC253NSR	so	NS	16	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1



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#### \*All dimensions are nominal

_	7 till dillitorioriorio di o riorimidi							
	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
	SN74HC253DBR	SSOP	DB	16	2000	356.0	356.0	35.0
	SN74HC253DR	SOIC	D	16	2500	356.0	356.0	35.0
	SN74HC253NSR	SO	NS	16	2000	356.0	356.0	35.0
	SN74HC253NSR	SO	NS	16	2000	356.0	356.0	35.0

# **PACKAGE MATERIALS INFORMATION**

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### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-88682012A	FK	LCCC	20	1	506.98	12.06	2030	NA
SN74HC253N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC253N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC253NE4	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC253NE4	N	PDIP	16	25	506	13.97	11230	4.32
SNJ54HC253FK	FK	LCCC	20	1	506.98	12.06	2030	NA

# D (R-PDS0-G16)

## PLASTIC SMALL OUTLINE

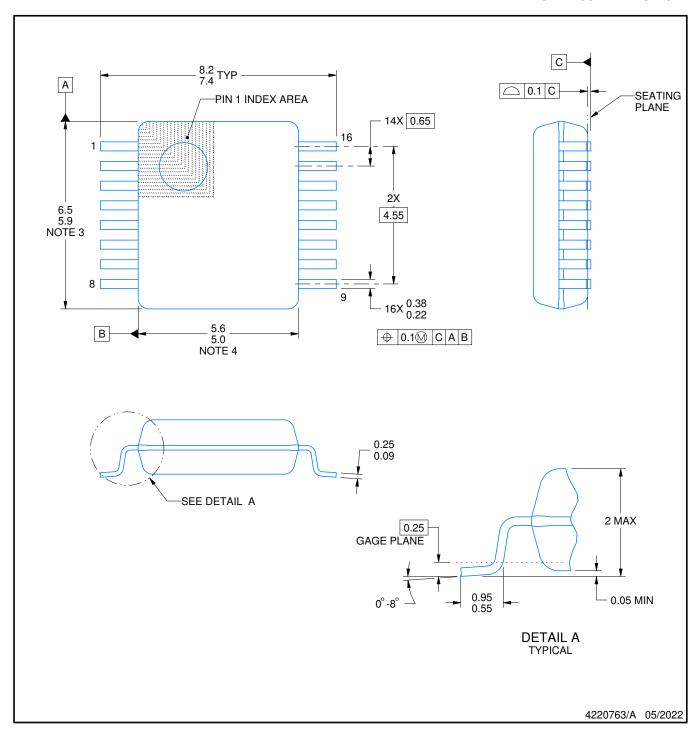


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.





SMALL OUTLINE PACKAGE



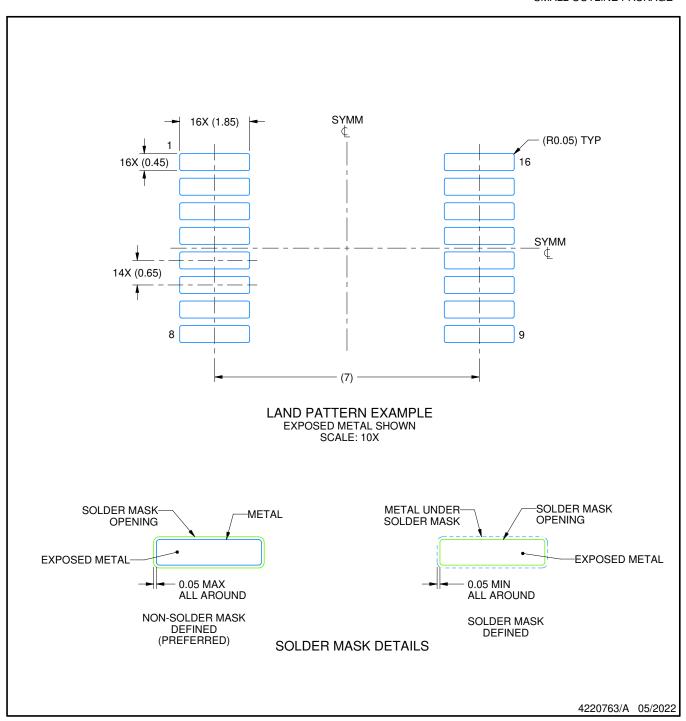
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-150.



SMALL OUTLINE PACKAGE



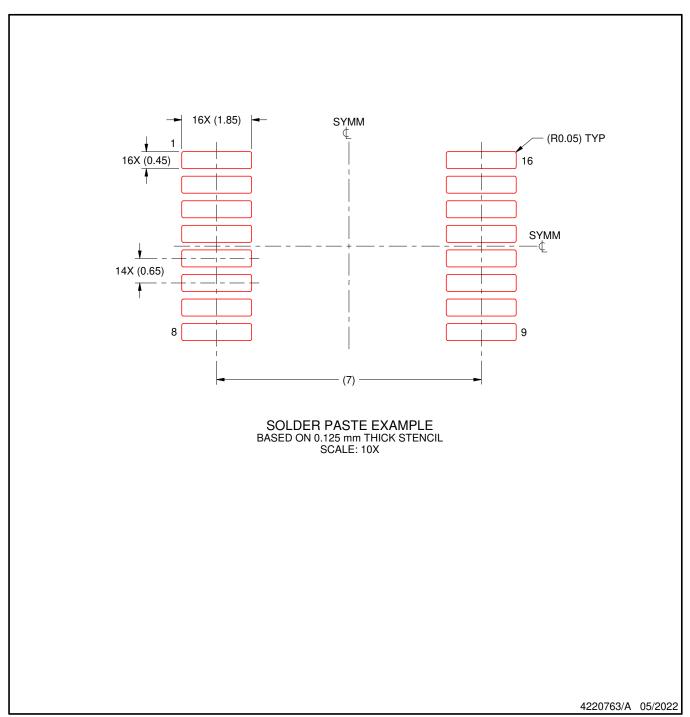
NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

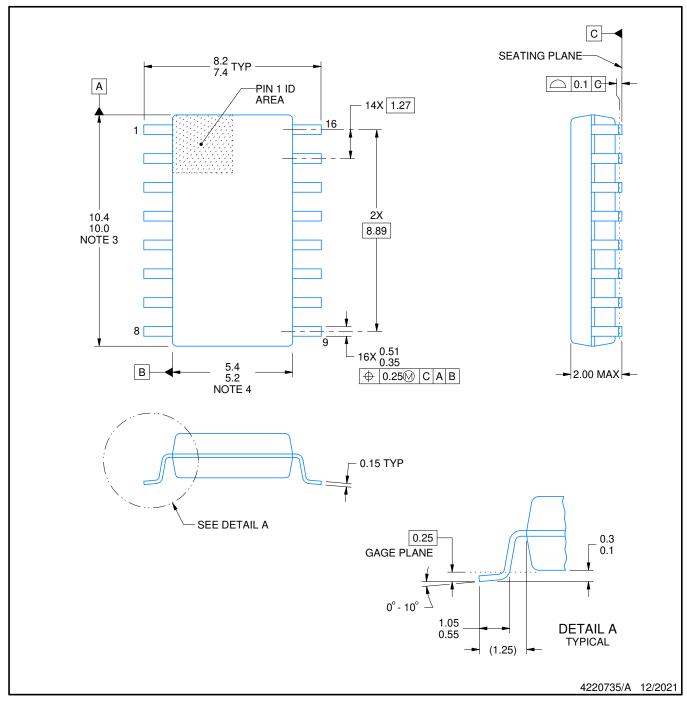


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOP



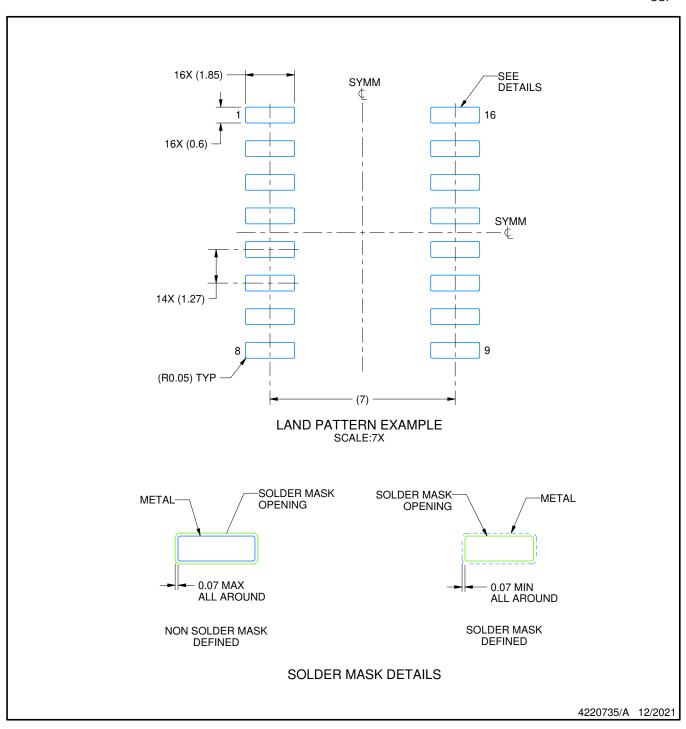
- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF



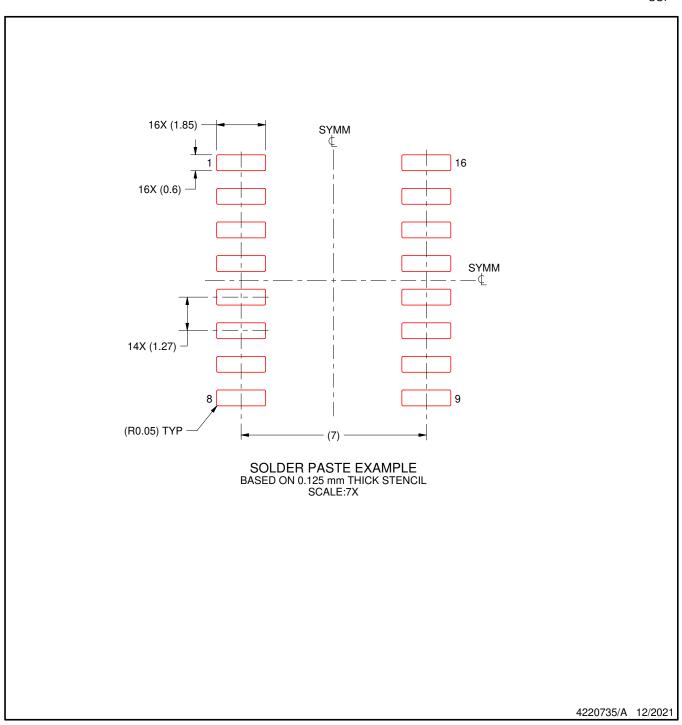
### NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOP



#### NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



# 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

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